

# Graphene 2.0: A new approach to making a unique material

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Since its discovery, graphene—an unusual and versatile substance composed of a single-layer crystal lattice of carbon atoms—has caused much excitement in the scientific community. Now, Nongjian(NJ) Tao, a researcher at the Biodesign Institute at Arizona State University has hit on a new way of making graphene, maximizing the material's enormous potential, particularly for use in high-speed electronic devices.

Along with collaborators from Germany's Max Planck Institute, the Department of Materials Science and Engineering, University of Utah, and Tsinghua University, Beijing, Tao created a graphene transistor composed of 13 benzene rings.

The molecule, known as a coronene, shows an improved electronic band gap, a property which may help to overcome one of the central obstacles to applying graphene technology for electronics. The group's work appears in the June 29 advanced online issue of *Nature Communications*.

Eventually, graphene components may find their way into a broad array of products, from lasers to ultra-fast computer chips; ultracapacitors with unprecedented storage capabilities; tools for microbial detection and diagnosis; photovoltaic cells; quantum computing applications and many others.

As the name suggests, graphene is closely related to graphite. Each time a pencil is drawn across a page, tiny fragments of graphene are shed. When properly magnified, the substance resembles an atomic-scale chicken wire. Sheets of the material possess exceptional electronic and optical properties, making it highly attractive for varied applications.

"Graphene is an amazing material, made of carbon atoms connected in a honeycomb structure," Tao says, pointing to graphene's huge electrical mobility—the ease with which electrons can flow through the material. Such high mobility is a critical parameter in determining the speed of components like transistors.

Producing usable amounts of graphene however, can be tricky. Until now, two methods have been favored, one in which single layer graphene is peeled from a multilayer sheet of graphite, using adhesive tape and the other, in which crystals of graphene are grown on a substrate, such as silicon carbide.

In each case, an intrinsic property of graphene must be overcome for the material

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to be suitable for a transistor. As Tao explains, "a transistor is basically a switch—you turn it on or off. A graphene transistor is very fast but the on/off ratio is very tiny." This is due to the fact that the space between the valence and conduction bands of the material—or band gap as it is known—is zero for graphene.

In order to enlarge the band gap and improve the on/off ratio of the material, larger sheets of graphene may be cut down to nanoscale sizes. This has the effect of opening the gap between valence and conductance bands and improving the on/off ratio, though such size reduction comes at a cost. The process is laborious and tends to introduce irregularities in shape and impurities in chemical composition, which somewhat degrade the electrical properties of the graphene. "This may not really be a viable solution for mass production," Tao observes.

Rather than a top down approach in which sheets of graphene are reduced to a suitable size to act as transistors, Tao's approach is bottom up—building up the graphene, molecular piece by piece. To do this, Tao relies on the chemical synthesis of benzene rings, hexagonal structures, each formed from 6 carbon atoms. "Benzene is usually an insulating material," Tao says. But as more such rings are joined together, the material's behavior becomes more like a semiconductor.

Using this process, the group was able to synthesize a coronene molecule, consisting of 13 benzene rings arranged in a well defined shape. The molecule was then fitted on either side with linker groups—chemical binders that allow the molecule to be attached to electrodes, forming a nanoscale circuit. An electrical potential was then passed through the molecule and the behavior, observed. The new structure displayed transistor properties, showing reversible on and off switches.

Tao points out that the process of chemical synthesis permits the fine-tuning of structures in terms of ideal size, shape and geometric structure, making it advantageous for commercial mass production. Graphene can also be made free of defects and impurities, thereby reducing electrical scattering and providing material with maximum mobility and carrier velocity, ideal for high-speed electronics.

In conventional devices, resistance is proportional to temperature, but in the graphene transistors by Tao et al., electron mobility is due to quantum tunneling, and remains temperature independent—a signature of coherent process.

The group believes they will be able to enlarge the graphene structures through chemical synthesis to perhaps hundreds of rings, while still maintaining a sufficient band gap to enable switching behavior. The research opens many possibilities for the future commercialization of this uncommon material, and its use in a new generation of ultra high-speed electronics.

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